





400V PNP SILICON PLANAR HIGH VOLTAGE TRANSISTOR IN SOT89

Features

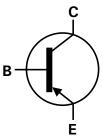
- BV_{CEO} > -400V
- I_C = -200mA high Continuous Current
- Low saturation voltage V_{CE(sat)} < -200mV @ -20mA
- Complementary NPN type: FCX458
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

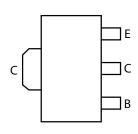
- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.05 grams (Approximate)







Device Symbol



Top View Pin Out

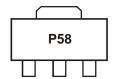
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX558TA	P58	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



P58 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	-400	V
Collector-Emitter Voltage	V _{CEO}	-400	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-200	mA
Peak Pulse Current	I _{CM}	-500	mA

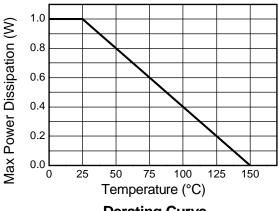
Thermal Characteristics

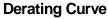
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{0JA}	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{ heta JL}$	10.01	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-65 to +150	°C

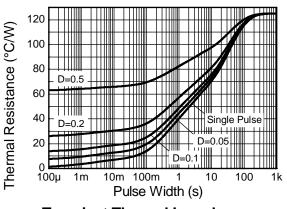
Notes:

- 5. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

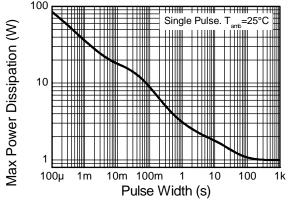
Thermal Characteristics and Derating Information







Transient Thermal Impedance



Pulse Power Dissipation





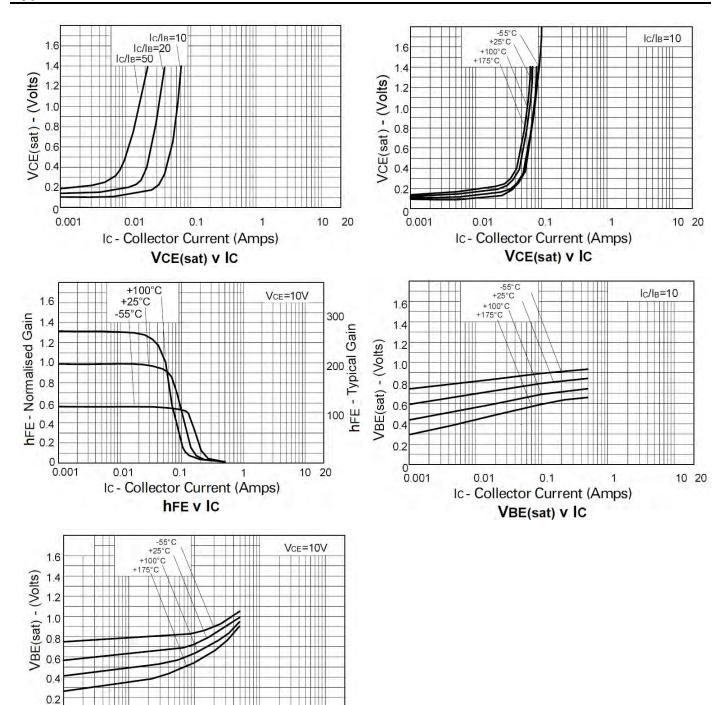
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-400	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-400	-	-	V	$I_C = -1 \text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I _{CBO}	-	-	-100	nA	V _{CB} = -320V
Emitter Cutoff Current	I _{EBO}	-	-	-100	nA	V _{EB} = -5V
Emitter Cutoff Current	I _{CES}	-	-	-100	nA	V _{CES} = -320V
DC current transfer Static ratio (Note 7)	h _{FE}	100 100 15	- - -	- 300 -	-	$I_{C} = -1 \text{mA}, V_{CE} = -10 \text{V}$ $I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}$ $I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	-	-	-0.2 -0.5	V	$I_C = -20mA$, $I_B = -2mA$ $I_C = -50mA$, $I_B = -6mA$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	-	-	-0.9	V	I _C = -50mA, I _B = -5mA
Base-Emitter Turn-on Voltage (Note 7)	V _{BE(on)}	-	-	-0.9	V	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
Transitional Frequency	f _T	50	-	-	MHz	$I_E = -10 \text{mA}, V_{CE} = -20 \text{V}$ f = 20 MHz
Output capacitance	C_{obo}	-	-	5	pF	$V_{CB} = -20V$, $f = 1MHz$,
Switching times	t _{on} t _{off}	-	95 1600	-	nS	$I_C = -50$ mA, $V_C = -100$ V $I_{B1} = -5$ mA, $I_{B2} = -10$ mA

Notes: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



0.1

Ic - Collector Current (Amps) **VBE(on) v IC**

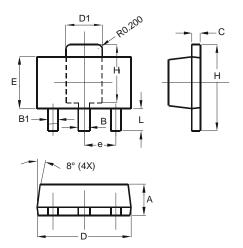
0.001

10 20



Package Outline Dimensions

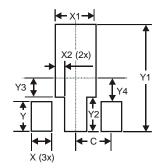
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
H	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All [All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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